

IN THE CLAIMS:

Claims 1-29 are pending in the application. All of the pending claims 1 through 29 are presented below. Please amend claims 1, 4, 5, 7, 12-15, 18-23, 25, 26, 27 and 29 as indicated below. Please cancel claims 8, 9, 16 and 17. Please add new claims 30-40. Please leave the remaining claims unchanged.

This listing of claims will replace all prior versions and listings of claims in the application.

1. (Currently Amended) A reflecting layer comprising:
Ag as a main component;
a 0.1-3.0 wt% first ~~element~~ metal selected from the group consisting of ~~Au~~, Pd, and Ru; and
a 0.1-3.0 wt% second ~~element~~ metal selected from the group consisting of Cu, Ti, Cr, Ta, Mo, Ni, Al, Nb, Au, Pd, and Ru, wherein the second ~~element~~ metal is different from the first ~~element~~ metal .
2. (Original) The reflecting layer according to claim 1, wherein the reflecting layer is formed by deposition.
3. (Original) The reflecting layer according to claim 1, wherein the reflecting layer is formed by sputtering.
4. (Currently Amended) A laminate comprising:
a substrate; and
a reflecting layer deposited on the substrate, wherein the reflecting layer includes Ag as a main component, a 0.1-3.0 wt% first ~~element~~ metal selected from the group consisting of ~~Au~~, Pd, and Ru, and a 0.1-3.0 wt% second ~~element~~ metal selected from the group

consisting of Cu, Ti, Cr, Ta, Mo, Ni, Al, Nb, Au, Pd, and Ru, wherein the second ~~element~~ metal is different from the first ~~element~~ metal.

5. (Currently Amended) The laminate according to claim 4, wherein the substrate is a plastic resin substrate.

6. (Original) The laminate according to claim 4, wherein the substrate is a glass substrate.

7. (Currently Amended) A laminate comprising:
a substrate;
a base film deposited on the substrate, wherein the base film is made of at least one of Si, Ta, Ti, Mo, Cr, Al, ITO (the composite oxide of indium oxide (In_2O_3) and tin oxide (SnO_2)), ~~ZnO~~ ZnO, SiO_2 , TiO_2 , Ta_2O_5 , ZrO_2 , In_2O_3 , SnO_2 , Nb_2O_5 , or MgO; and
an Ag-containing reflecting layer deposited on the base film, the Ag-containing reflecting layer comprising Ag as a main component, a 0.1-3.0 wt% first metal selected from the group consisting of Pd, and Ru, and a 0.1-3.0 wt% second metal selected from the group consisting of Cu, Ti, Cr, Ta, Mo, Ni, Al, Nb, Au, Pd, and Ru, wherein the second metal is different from the first metal.

8. (Canceled)

9. (Canceled)

10. (Original) The laminate according to claim 7 further comprising a coating layer deposited on the reflecting layer, wherein the coating layer includes In_2O_3 as a main component and at least one of SnO_2 , Nb_2O_5 , SiO_2 , MgO and Ta_2O_5 .

11. (Original) The laminate according to claim 7, wherein the substrate is a glass substrate.
12. (Currently Amended) The laminate according to claim 7, wherein the base film is made of at least one of Si, Ta, Ti, Mo, Cr, ~~or~~ and Al.
13. (Currently Amended) The laminate according to claim 7, wherein the base film is made of at least one of ITO, ~~ZnO₂~~, ZnO, SiO₂, TiO₂, Ta₂O₅, ZrO₂, In₂O₃, SnO₂, Nb₂O₅, ~~or~~ and MgO.
14. (Currently Amended) The laminate according to claim 13, wherein the substrate is a plastic resin substrate.
15. (Currently Amended) A laminate comprising:
an Ag-containing reflecting layer, the Ag-containing reflecting layer comprising Ag as a main component, a 0.1-3.0 wt% first metal selected from the group consisting of Pd, and Ru, and a 0.1-3.0 wt% second metal selected from the group consisting of Cu, Ti, Cr, Ta, Mo, Ni, Al, Nb, Au, Pd, and Ru, wherein the second metal is different from the first metal;
and
a coating layer deposited on the reflecting layer, wherein the coating layer includes In₂O₃ as a main component and at least one of SnO₂, Nb₂O₅, SiO₂, MgO, and Ta₂O₅.
16. (Canceled)
17. (Canceled)

18. (Currently Amended) The laminate according to claim 4, wherein the laminate is ~~building glass~~ for building materials or a reflector or a reflective wiring electrode for a liquid crystal display device.

19. (Currently Amended) The laminate according to claim 7, wherein the laminate is ~~building glass~~ for building materials or a reflector or a reflective wiring electrode for a liquid crystal display device.

20. (Currently Amended) The laminate according to claim 10, wherein the laminate is ~~building glass~~ for building materials or a reflector or a reflective wiring electrode for a liquid crystal display device.

21. (Currently Amended) The laminate according to claim 15, wherein the laminate is ~~building glass~~ for building materials or a reflector or a reflective wiring electrode for a liquid crystal display device.

22. (Currently Amended) A liquid crystal display device comprising a reflecting layer, wherein the reflecting layer includes Ag as a main component, a 0.1-3.0 wt% first ~~element~~ metal selected from the group consisting of ~~Au~~, Pd, and Ru, and a 0.1-3.0 wt% second ~~element~~ metal selected from the group consisting of Cu, Ti, Cr, Ta, Mo, Ni, Al, Nb, Au, Pd, and Ru, wherein the second ~~element~~ metal is different from the first ~~element~~ metal.

23. (Currently Amended) A liquid crystal display device comprising a laminate, wherein the laminate includes a substrate, a base film deposited on the substrate, and an Ag-containing reflecting layer deposited on the base film, the Ag-containing reflecting layer comprising Ag as a main component, a 0.1-3.0 wt% first metal selected from the group consisting of Pd, and Ru, and a 0.1-3.0 wt% second metal selected from the group consisting of Cu, Ti, Cr, Ta, Mo, Ni, Al, Nb, Au, Pd, and Ru, wherein the second metal is different from the

first metal, wherein the base film is made of at least one of Si, Ta, Ti, Mo, Cr, Al, ITO (the composite oxide of indium oxide (In_2O_3) and tin oxide (SnO_2)), ~~ZnO₂~~, ZnO, SiO_2 , TiO_2 , Ta_2O_5 , ZrO_2 , In_2O_3 , SnO_2 , Nb_2O_5 , ~~or~~ and MgO .

24. (Original) The liquid crystal display device according claim 23, wherein the laminate further includes a coating layer deposited on the reflecting layer, wherein the coating layer includes In_2O_3 as a main component and at least one of SnO_2 , Nb_2O_5 , SiO_2 , MgO and Ta_2O_5 .

25. (Currently Amended) A liquid crystal display device comprising a laminate, wherein the laminate includes an Ag-containing reflecting layer, wherein the Ag-containing reflecting layer comprises Ag as a main component, a 0.1-3.0 wt% first metal selected from the group consisting of Pd, and Ru, and a 0.1-3.0 wt% second metal selected from the group consisting of Cu, Ti, Cr, Ta, Mo, Ni, Al, Nb, Au, Pd, and Ru, wherein the second metal is different from the first metal, and a coating layer deposited on the reflecting layer, wherein the coating layer includes In_2O_3 as a main component and at least one of SnO_2 , Nb_2O_5 , SiO_2 , MgO , and Ta_2O_5 .

26. (Currently Amended) A portable terminal device comprising a liquid crystal display device having a reflecting layer, wherein the reflecting layer includes Ag as a main component, a 0.1-3.0 wt% first ~~element~~ metal selected from the group consisting of ~~Au~~, Pd, and Ru, and a 0.1-3.0 wt% second ~~element~~ metal selected from the group consisting of Cu, Ti, Cr, Ta, Mo, Ni, Al, Nb, Au, Pd, and Ru, wherein the second ~~element~~ metal is different from the first ~~element~~ metal.

27. (Currently Amended) A portable terminal device comprising a liquid crystal display device having a laminate, wherein the laminate includes a substrate, a base film deposited on the substrate, and an Ag-containing reflecting layer deposited on the base film,

wherein the base film is made of at least one of Si, Ta, Ti, Mo, Cr, Al, ITO(the composite oxide of indium oxide (In_2O_3) and tin oxide (SnO_2)), ~~ZnO~~, ZnO, SiO_2 , TiO_2 , Ta_2O_5 , ZrO_2 , In_2O_3 , SnO_2 , Nb_2O_5 , ~~or~~ and MgO , and wherein the Ag-containing reflecting layer comprises Ag as a main component, a 0.1-3.0 wt% first metal selected from the group consisting of Pd and Ru, and a 0.1-3.0 wt% second metal selected from the group consisting of Cu, Ti, Cr, Ta, Mo, Ni, Al, Nb, Au, Pd, and Ru, wherein the second metal is different from the first metal.

28. (Original) The portable terminal device according claim 27, wherein the laminate further includes a coating layer deposited on the reflecting layer, wherein the coating layer includes In_2O_3 as a main component and at least one of SnO_2 , Nb_2O_5 , SiO_2 , MgO and Ta_2O_5 .

29. (Currently Amended) A portable terminal device comprising a liquid crystal display device having a laminate, wherein the laminate includes an Ag-containing reflecting layer and a coating layer deposited on the reflecting layer, wherein the coating layer includes In_2O_3 as a main component and at least one of SnO_2 , Nb_2O_5 , SiO_2 , MgO , and Ta_2O_5 , and wherein the Ag-containing reflecting layer comprises Ag as a main component, a 0.1-3.0 wt% first metal selected from the group consisting of Pd and Ru, and a 0.1-3.0 wt% second metal selected from the group consisting of Cu, Ti, Cr, Ta, Mo, Ni, Al, Nb, Au, Pd, and Ru, wherein the second metal is different from the first metal

30. (New) A reflecting layer comprising:
Ag as a main component;
a 0.1-3.0 wt% Pd as a first metal; and
a 0.1-3.0 wt% Cu as a second metal.

31. (New) A reflecting layer comprising:
Ag as a main component;
a 0.1-3.0 wt% Au as a first metal; and
a 0.1-3.0 wt% second metal selected from the group consisting of Ti, Cr, Ta, Mo, Ni, Al, Nb, Pd, and Ru.

32. (New) A laminate comprising:
a substrate; and
a reflecting layer deposited on the substrate, wherein the reflecting layer includes Ag as a main component, a 0.1-3.0 wt% of Au as a first metal, and a 0.1-3.0 wt% second metal selected from the group consisting of Ti, Cr, Ta, Mo, Ni, Al, Nb, Pd, and Ru.

33. (New) A laminate comprising:
a substrate;
a base film deposited on the substrate, wherein the base film is made of at least one of Si, Ta, Ti, Mo, Cr, Al, ITO (the composite oxide of indium oxide (In_2O_3) and tin oxide (SnO_2)), ZnO, SiO_2 , TiO_2 , Ta_2O_5 , ZrO_2 , In_2O_3 , SnO_2 , Nb_2O_5 , or MgO; and
an Ag-containing reflecting layer deposited on the base film, the Ag-containing reflecting layer comprising Ag as a main component, a 0.1-3.0 wt% Au as a first metal, and a 0.1-3.0 wt% second metal selected from the group consisting of Ti, Cr, Ta, Mo, Ni, Al, Nb, Pd, and Ru.

34. (New) A laminate comprising:
an Ag-containing reflecting layer, the Ag-containing reflecting layer comprising Ag as a main component, a 0.1-3.0 wt% Au as a first metal, and a 0.1-3.0 wt% second metal selected from the group consisting of Ti, Cr, Ta, Mo, Ni, Al, Nb, Pd, and Ru; and
a coating layer deposited on the reflecting layer, wherein the coating layer includes In_2O_3 as a main component and at least one of SnO_2 , Nb_2O_5 , SiO_2 , MgO, and Ta_2O_5 .

35. (New) A liquid crystal display device comprising a reflecting layer, wherein the reflecting layer includes Ag as a main component, a 0.1-3.0 wt% Au as a first metal, and a 0.1-3.0 wt% second metal selected from the group consisting of Ti, Cr, Ta, Mo, Ni, Al, Nb, Pd, and Ru.

36. (New) A liquid crystal display device comprising a laminate, wherein the laminate includes a substrate, a base film deposited on the substrate, and an Ag-containing reflecting layer deposited on the base film, the Ag-containing reflecting layer comprising Ag as a main component, a 0.1-3.0 wt% Au as a first metal, and a 0.1-3.0 wt% second metal selected from the group consisting of Ti, Cr, Ta, Mo, Ni, Al, Nb, Pd, and Ru, wherein the base film is made of at least one of Si, Ta, Ti, Mo, Cr, Al, ITO (the composite oxide of indium oxide (In_2O_3) and tin oxide (SnO_2)), ZnO, SiO_2 , TiO_2 , Ta_2O_5 , ZrO_2 , In_2O_3 , SnO_2 , Nb_2O_5 , ~~or~~ and MgO.

37. (New) A liquid crystal display device comprising a laminate, wherein the laminate includes an Ag-containing reflecting layer, wherein the Ag-containing reflecting layer comprises Ag as a main component, a 0.1-3.0 wt% Au as a first metal, and a 0.1-3.0 wt% second metal selected from the group consisting of Ti, Cr, Ta, Mo, Ni, Al, Nb, Pd, and Ru, and a coating layer deposited on the reflecting layer, wherein the coating layer includes In_2O_3 as a main component and at least one of SnO_2 , Nb_2O_5 , SiO_2 , MgO, and Ta_2O_5 .

38. (New) A portable terminal device comprising a liquid crystal display device having a reflecting layer, wherein the reflecting layer includes Ag as a main component, a 0.1-3.0 wt% Au as a first metal, and a 0.1-3.0 wt% second metal selected from the group consisting of Ti, Cr, Ta, Mo, Ni, Al, Nb, Pd, and Ru.

39. (New) A portable terminal device comprising a liquid crystal display device having a laminate, wherein the laminate includes a substrate, a base film deposited on the substrate, and an Ag-containing reflecting layer deposited on the base film, wherein the base film is made of at least one of Si, Ta, Ti, Mo, Cr, Al, ITO(the composite oxide of indium oxide (In_2O_3) and tin oxide (SnO_2)), ZnO, SiO_2 , TiO_2 , Ta_2O_5 , ZrO_2 , In_2O_3 , SnO_2 , Nb_2O_5 , and MgO, and wherein the Ag-containing reflecting layer comprises Ag as a main component, a 0.1-3.0 wt% Au as a first metal, and a 0.1-3.0 wt% second metal selected from the group consisting of Ti, Cr, Ta, Mo, Ni, Al, Nb, Pd, and Ru.

40. (New) A portable terminal device comprising a liquid crystal display device having a laminate, wherein the laminate includes an Ag-containing reflecting layer and a coating layer deposited on the reflecting layer, wherein the coating layer includes In_2O_3 as a main component and at least one of SnO_2 , Nb_2O_5 , SiO_2 , MgO, and Ta_2O_5 , and wherein the Ag-containing reflecting layer comprises Ag as a main component, a 0.1-3.0 wt% Au as a first metal, and a 0.1-3.0 wt% second metal selected from the group consisting of Ti, Cr, Ta, Mo, Ni, Al, Nb, Pd, and Ru.